Electron energy-loss and photoemission studies of solid C_{84}

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The electronic structure of pure solid C_{84} has been studied using high-energy electron energyloss spectroscopy in transmission and photoemission spectroscopy. Information is obtained on the occupied and unoccupied σ and π bands. The reduced degeneracy of the electronic states and smaller band gap of C_{84} in comparison with C_{60} are evident, as well as the excitonic nature of the transition across the band gap of solid C_{84} .

I. INTRODUCTION

Several years after the first preparation of bulk quantities of C_{60} ,¹ it still remains a formidable practical challenge to separate and purify macroscopic amounts of the higher fullerenes C_x , particularly for x > 70. Consequently, in contrast to the case of C_{60} and C_{70} , there have been relatively few studies of the structure and properties of the third most abundant fullerene, C₈₄, in the solid state. However, advances in separation techniques have meant that purified higher fullerenes have become available and have been studied using a number of techniques including ¹³C NMR,² ultraviolet/visible absorption,³ and ultraviolet⁴ (uv) and x-ray photoelectron spectroscopy (XPS).⁵ Ordered thin films of C₈₄ can be grown on mica, which are face centered cubic (fcc) with a lattice constant $a_0 = 15.9$ Å.⁶ Recently, results from an electron energyloss spectroscopy (EELS) in transmission study of C_{84} were reported.⁷

There are a large number of possible fullerene structural isomers of C₈₄, but it appears from NMR studies that the samples from different laboratories are remarkably similar.² The consensus is that there are $D_{2d}(23)$ and $D_2(5 \text{ or } 22)$ isomers⁸ in the ratio 1:2, with the $D_2(22)$ isomer thought to be the energetically favored D_2 form.⁹

In this paper, we report an investigation of the solid state electronic structure of well characterized C_{84} thin films using EELS in transmission and high-resolution photoemission spectroscopy (PES). Our results show that the general features of the electronic structure of C_{84} are similar or analogous to those of C_{60} . However, in comparison with C_{60} , the lower molecular symmetry and correspondingly lower degeneracy of the electronic levels do result in significant reductions in both the sharpness of the electronic bands in C_{84} , and the magnitude of the fundamental gap.

II. EXPERIMENT

 C_{84} of purity 97.5% by weight was prepared using state-of-the-art liquid chromatographic treatment of fullerene-containing carbon soot produced using the Krätschmer/Huffman gas discharge method.¹ Details of the separation, purification, and characterization procedures will be published elsewhere.¹⁰

The thin films for EELS investigations (~1000 Å thick) were prepared by sublimation of C_{84} at ~550 °C from a copper crucible onto KBr single crystal substrates held at 140 °C in a vacuum chamber with base pressure 5×10^{-9} mbar. The films were subsequently floated off the substrates in distilled water, mounted on standard electron microscopy grids, and immediately transferred to the EELS spectrometer (base pressure 3×10^{-9} mbar) in which they were annealed in vacuo at 350 °C. The same free-standing films were also characterized using transmission electron microscopy (TEM). The energy-loss as well as electron diffraction data were recorded at room temperature in transmission using a spectrometer¹¹ having a primary beam energy of 170 keV. The energy resolution of the spectrometer was set to 0.14 eV. The momentum resolution was chosen to be 0.04 $Å^{-1}$ for the valence band excitations and elastic scattering (electron diffraction) measurements, and 0.20 Å⁻¹ for the C 1s core excitations.

For the photoemission measurements, C_{84} was sublimed from a well-degassed Knudsen cell at 500 °C onto a freshly evaporated gold film held at room temperature. The film thickness was ~40 Å, deposited at a rate of ~0.6 Å/min, as determined by a quartz crystal thickness monitor. After deposition, the C_{84} was annealed at 150 °C for 1 h to improve crystallinity. The photoemission spectra were recorded using He I radiation ($h\nu = 21.22$ eV), with a total energy resolution of 25 meV. Both the resolution and the position of the Fermi level of the spectrometer (and hence the sample) were monitored using measurements on a clean Au film at 15 K. The data shown here contain no correction for He I satellite lines.

III. RESULTS

From analysis of the TEM data (not shown), as well as electron diffraction experiments carried out *in situ* in the EELS spectrometer, the C₈₄ thin films grown on KBr present a (111) surface of a face centered cubic (fcc) lattice with $a_0 = 15.8$ Å. Within error, this is identical to the result of Saito *et al.*⁶ from films grown on mica. The TEM images revealed that the films were comprised of mainly single-domain ordered regions of average extension ~700 Å, which is slighly larger than the domain size reported by Saito *et al.*⁶

In Fig. 1 we show the loss function $\text{Im}(-1/\epsilon)$ of C₈₄ for small momentum transfer $(q=0.1 \text{ Å}^{-1})$. After subtraction of the contributions from the direct beam and multiple scattering,¹² the absolute value of the loss function can be obtained from a Kramers-Kronig analysis. This provides the real and imaginary part of the dielectric function, ϵ_1 and ϵ_2 , respectively. These quantities are also shown in Fig. 1. For the purposes of comparison with present and future optical data, we have also evaluated the optical conductivity $\sigma(\omega)$. This can be seen in the bottom panel of Fig. 1.

The low-energy excitations of C_{84} shown in Fig. 1 contain two main groups of features.⁷ The first of these is located at energies less than $\sim 10 \text{ eV}$ with a maximum at



FIG. 1. The loss function $\text{Im}(-1/\epsilon)$, the real and imaginary parts of the dielectric constant, ϵ_1 and ϵ_2 , and the optical conductivity $\sigma(\omega)$ of solid C₈₄. The momentum transfer is 0.1 Å⁻¹.

 $\sim 6.2 \mathrm{eV}$ in the loss function, while the second set of features at higher energy is centered on a peak at $\sim 24.6 \mathrm{eV}$. We note that a clear gap is observed at low energy, with an onset in the loss function at $1.2 \pm 0.1 \mathrm{eV}$, in agreement with Kuzuo *et al.*⁷

The C 1s core level excitations of C₈₄ can be seen in Fig. 2. Neglecting the effect of the core hole, these excitations from the C 1s level into C 2p-derived bands are related to the unoccupied density of states (DOS) having C 2p character. The onset of the C 1s transitions in C₈₄ is 283.7 eV. The first peak is found at 284 eV, followed by a broad peak with a maximum at ~ 285.9 eV which has three shoulders at lower energy (~ 284.7, ~ 285.2, and ~ 285.6 eV). There then follows a weak maximum at ~ 287.3 eV and a steplike structure at ~ 290 eV.

The photoemission spectra of C_{84} as a function of temperature are shown in Fig. 3. In the room temperature spectrum, the onset of spectral weight is located at a binding energy (BE) of 1.3 eV, with maxima at 2.1, 3.4, 5.4, 6.4, and 7.8 eV BE. Further bands are evident as shoulders on the main peaks, located at 1.7, 3.1, 4.5, 5.1, and 8.5 eV BE. These results are broadly in agreement with an earlier photoemission study of C_{84} ,⁴ although the superior energy resolution and statistics of the present data allow the discrimination of more features with greater certainty. The widths of the leading features are estimated from peak fitting to be 1.3 and 1.4 eV. It can be seen that there are no great changes in the spectral profile across the measured temperature range.

IV. DISCUSSION

Before discussing the valence band excitations shown in Fig. 1 in detail, it would be useful to consider the assumptions made in applying the Kramers-Kronig analysis to the loss function. To perform the Kramers-Kronig analysis, the absolute scale of the coss function has to be known. This is usually determined either from prior knowledge of the value of $\epsilon_1(0)$ from another source, or from the value required for agreement with the oscillator strength sum rule, in which the effective density of valence electrons, $n_{\rm eff}$, is related to the imaginary part of the dielectric function, ϵ_2 , by the following relation:

$$n_{\text{eff}} = \frac{m}{2\pi^2 e^2} \int_0^\infty E\epsilon_2(E) dE, \qquad (1)$$



FIG. 2. C 1s absorption edge for C_{84} .



FIG. 3. He I photoemission spectra of C_{84} as a function of temperature. The solid lines are intended as a guide to the eye.

in which E is the energy and m the electron mass. For C_{60} , the value of $\epsilon_1(0) = 4.2$ is known from ellipsometric measurements.¹³ This allows the experimental derivation of n_{eff} for C_{60} ,¹⁴ which is found to be 10% lower than that arrived at from the total number of valence electrons $(4n_{\rm C}, \text{ where } n_{\rm C} \text{ is the number of carbon atoms})$ and the volume of the unit cell.¹⁵ To the best of our knowledge no direct experimental value of $\epsilon_1(0)$ has been determined for C_{84} ; thus, by analogy with C_{60} , we scale the loss function using the sum rule (1), taking $n_{\rm eff}$, as in C_{60} , to be 10% lower than the value derived from $4n_{\rm C}$ and the unit cell volume. This results in $\epsilon_1(0) = 5-6$ for C_{84} , taking a fcc unit cell with $a_0 = 15.8$ Å. This value of $\epsilon_1(0)$ is higher than that of C_{60} , which is in keeping with the smaller band gap of the higher fullerene.

The loss function of C₈₄ seen in Fig. 1 displays two main features familiar from the spectra of other π -bonded carbon systems such as C_{60} and C_{70} ,¹⁴ graphite,¹¹ and polyacetylene.¹¹ In these compounds, the prominent peak in the region of 20 eV (24.6 eV in C₈₄) is ascribed to a collective excitation of the total $\pi + \sigma$ valence electron system. The preceding structure with a maximum near 6 eV is the corresponding plasmon of the π electrons alone (this appears at ~ 6.2 eV in C₈₄). In C₈₄, both of these features appear at slightly different energies than in C₆₀. In common with C₆₀, the energy of the π and $\pi + \sigma$ plasmons observed in C₈₄ cannot be correctly reproduced within calculations based on the Drude model alone.^{14,16} Assuming the same electron density as was used in the Kramers-Kronig analysis of the loss function discussed above, the Drude model predicts the energy of the π + σ plasmon of $\rm C_{84}$ to be $\sim~20$ eV, some 5 eV lower than is experimentally observed. However, the energy of the plasmon, E_p , can be more satisfactorily calculated using a Drude-Lorentz model,¹⁴ which gives $E_p = (E_g^2 + 4\pi n_{\text{eff}}e^2\hbar^2/m)^{1/2}$, in which the presence of oscillators at an energy greater than zero, E_g , is included. In this model, we achieve good agreement with the experimental plasmon energy (25 eV) taking $E_g \sim 14$ eV. This value is reasonable in light of the optical conductivity data shown in Fig. 1, in which the largest contribution to the oscillator strength, due to $\sigma \rightarrow \sigma^*$ transitions, is

situated between ~ 8 and 35 eV and has a maximum at ~14 eV. The value of the onset in the loss function closely resembles the gap value obtained from uv absorption measurements of C_{84} in solution (~ 1.2 eV),³ as well as that from C 1s core level photoemission shakeup satellite structure (~ 1.4 eV).⁵ The similarity of the size of the solution and solid state gap points to the molecular nature of the latter transition in solid C_{84} . These gap values are smaller than those of solid C_{60} ,^{14,17} and result from the reduction of the π - π^* energy level separation as a consequence of the lower degeneracy in the higher fullerene.

The C 1s absorption spectrum shown in Fig. 2 represents transitions from the C 1s core level into the bands derived from the unoccupied π^* and σ^* molecular orbitals of the C_{84} molecules in the solid [i.e., C 1s \rightarrow LUMO (lowest unoccupied molecular orbital), LUMO+1, LUMO+2, etc.]. There is a pronounced minimum between the first feature due to C $1s \rightarrow LUMO$ transitions and the higher excitation channels, together with clear fine structure in the latter. These details were not observed in an earlier EELS study of C_{84} .⁷ However, the C 1s absorption spectrum of C₈₄ still shows less distinct spectral features than is the case for C_{60} .¹⁴ This is a consequence of the lower symmetry of C_{84} with respect to C_{60} , and thus of the lower degeneracy of the electronic levels of the higher fullerene. In particular, the structure observed at energies above the C $1s \rightarrow$ LUMO peak (i.e., between 286 and 290 eV) in C_{60} is smeared out in C_{84} . Additionally, the relative intensity of the first peak (C $1s \rightarrow LUMO$) is also lower in C₈₄ than in C₆₀. This last point results, at least in part, from the presence of a minimum of 32 inequivalent carbon sites in the solid resulting from the C₈₄ isomer mixture in the sample. From analogy with graphite¹¹ and C_{60} ,¹⁴ the steplike structure at $\sim 290 \text{ eV}$ is assigned to the onset of transitions from the C 1s level to the unoccupied σ^* -derived bands.

Turning to the photoemission spectra shown in Fig. 3, the width of the features in the C₈₄ spectrum, and in particular the two peaks at lowest BE, is greater than in C₆₀ [in which the highest occupied molecular orbital (HOMO) and HOMO-1 have widths 1.0 and 1.2 eV, respectively¹⁸]. At this stage it is difficult to definitively assign the observed peaks in the photoemission spectrum to bands derived from particular molecular orbitals of C_{84} . This follows from both the polyisomeric nature of the sample, and the high degree of overlap between the different features in the spectrum (which in turn results from the relatively low degeneracy of the molecular energy levels of C_{84}). However, by analogy with C_{60} , and together with the photon-energy-dependent photoemission data of C₈₄ from Hino et al.,⁴ it would appear likely that at least the first two features are derived from the uppermost groups of π -bonding molecular orbitals.

The onset of the occupied DOS of C_{84} seen in Fig. 3 is at 1.3 eV BE. In inverse photoemission (IPES), the onset of the first unoccupied band of C_{84} is found at 0.4 eV above E_F .¹⁹ Thus the gap from PES and IPES is ~ 1.7 eV. This quantity is a measure of the gap between the (N-1) and (N+1) electronic states, where N is the number of electrons in the ground state electronic configuration of C_{84} , and represents the energy gap that needs to be overcome in the transport of electrical current through the material. In C_{60} , this so-called transport gap is ~ 2.3 eV and is some 0.8 eV higher than the gap value from optical or EELS studies of solid C_{60} .^{20,21} Thus, as expected, C_{84} has a smaller gap between the occupied and unoccupied bands derived from the molecular orbitals than C_{60} . Additionally, in C_{60} this discrepancy between the PES-IPES gap and the EELS gap is taken as evidence that the low-energy excitations correspond to Frenkel-type molecular excitons. In the case of C_{84} , the transport gap from PES-IPES is ~ 0.5 eV greater than that from EELS and thus it would seem that in this case too the low-energy excitation observed in EELS is excitonic in nature. This conclusion is further strengthened by the fact that the size of the gap of solid C_{84} is the same as that observed in solution.

By analogy with other fullerenes, it would be reasonable to expect that the quasispherical shape and weak intermolecular interactions in solid C₈₄ would result in a significant degree of temperature-dependent orientational disorder. It is seen from Fig. 3 that the PES profile of C_{84} remains essentially unchanged on either heating (415 K) or cooling (10 K) from room temperature. This result does not necessarily preclude the existence of temperature-dependent orientational disorder in C_{84} , as similar behavior has been observed for C_{60} , in which the expected changes in the occupied DOS resulting from the solid state phase transitions were not observed in highresolution PES.¹⁸ This was suggested to be a result of a smearing out of the expected fine structure due to the excitation of phonons, possible Jahn-Teller distortion, or the existence of satellites resulting from the effects of strong correlation.¹⁸ The same potential broadening mechanisms may also lead to the lack of any observed temperature dependence in the PES spectra of C_{84} . In

addition, the existence of at least two isomers may preclude the observation of phase transitions related to orientational ordering, due to the extra disorder inherent in the mixed isomer system. The apparent temperature independence of the PES profiles of C_{60} and C_{84} is in contrast to the case of C_{70} , in which several features show an enhancement in intensity above room temperature, with increasing broadening of these features as the temperature is decreased to 40 K.²²

V. CONCLUSIONS

The present study of the electronic structure of thin films of C_{84} using EELS and PES has revealed the general similarities of the electronic structures of C_{84} and C_{60} . However, the lower symmetry and thus degeneracy of the electronic levels of the former leads to the broadening of many of the features in the spectra in comparison to C_{60} . The lifting of the degeneracy in C_{84} is also evident in the smaller gap observed in the loss function (1.2 eV) compared to C_{60} . In common with C_{60} , the gap excitation in solid C_{84} is excitonic in character.

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